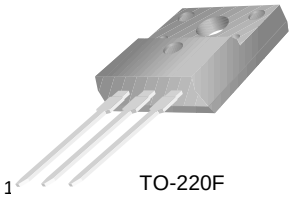
FAIRCHILD
SEMICONDUCTOR®

KSC5367F

High Voltage and High Reliability

- High speed Switching
- Wide Safe Operating Area
- High Collector-Base Voltage



TO-220F

1.Base 2.Collector 3.Emitter

NPN Triple Diffused Planar Silicon Transistor

Absolute Maximum Ratings T_C=25°C unless otherwise noted

Symbol	Parameter	Value	Units
V_{CBO}	Collector-Base Voltage	1600	V
V_{CEO}	Collector-Emitter Voltage	800	V
V_{EBO}	Emitter-Base Voltage	12	V
I_C	Collector Current (DC)	3	A
I_{CP}	*Collector Curren (Pulse)	6	A
I_B	Base Current (DC)	2	A
I_{BP}	*Base Current (Pulse)	4	A
P_C	Power Dissipation(T_C=25°C)	40	W
T_J	Junction Temperature	150	°C
T_{STG}	Storage Temperature	- 65 ~ 150	°C

* Pulse Test: Pulse Width=5ms, Duty Cycle≤10%

Thermal Characteristics T_C=25°C unless otherwise noted

Symbol	Characteristics		Rating	Unit
$R_{\theta jc}$	Thermal Resistance	Junction to Case	3.1	°C/W
$R_{\theta ja}$		Junction to Ambient	62.5	

Electrical Characteristics T_C=25°C unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Typ.	Max.	Units
BV_{CBO}	Collector-Base Breakdown Voltage	I_C = 0.5mA, I_E = 0	1600	-	-	V
BV_{CEO}	Collector-Emitter Breakdown Voltage	I_C = 5mA, I_B = 0	800	-	-	V
BV_{EBO}	Emitter-Base Breakdown Voltage	I_C =0.5mA, I_C = 0	12	-	-	V
I_{CBO}	Collector Cut-off Current	V_{CB} = 1,600V, I_E = 0	-	-	20	μA
I_{EBO}	Emitter Cut-off Current	V_{EB} = 12V, I_C = 0	-	-	20	μA
h_{FE1} h_{FE2}	DC Current Gain	V_{CE} = 3V, I_C = 0.4A V_{CE} = 10V, I_C = 5mA	12 8	- -	35 -	
V_{CE}(sat)	Collector-Emitter Saturation Voltage	I_C = 250mA, I_B = 25mA I_C = 500mA, I_B = 50mA I_C = 1A, I_B = 0.2A	- - -	- - -	2.5 4.0 2.5	V V V
V_{BE}(sat)	Base-Emitter Saturation Voltage	I_C = 500mA, I_B = 50mA	-	-	1.5	V
C_{ob}	Output Capacitance	V_{CB} =10V, I_E = 0, f = 1MHz	-	40	-	pF
t_{ON}	Turn ON Time	V_{CC} = 125V, I_C = 0.5A I_{B1} = 42mA, I_{B2} = -333mA R_L = 250Ω	-	-	0.5	μs
t_{STG}	Storage Time			-	2.2	μs
t_F	Falling Time		-	-	0.5	μs
t_{ON}	Turn ON Time	V_{CC} = 250V, I_C = 1A I_{B1} = 0.2A, I_{B2} = -0.4A R_L = 250Ω	-	-	0.5	μs
t_{STG}	Storage Time		-	-	4.0	μs
t_F	Falling Time		-	-	0.5	μs

Typical Characteristics

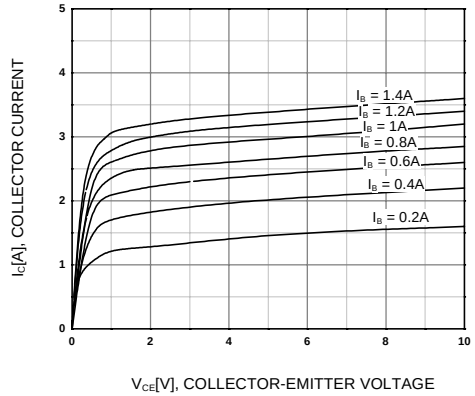


Figure 1. Static Characteristic

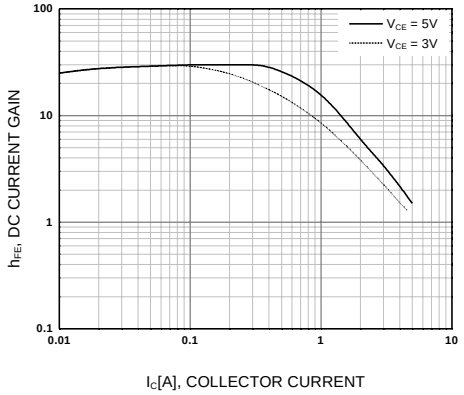


Figure 2. DC current Gain

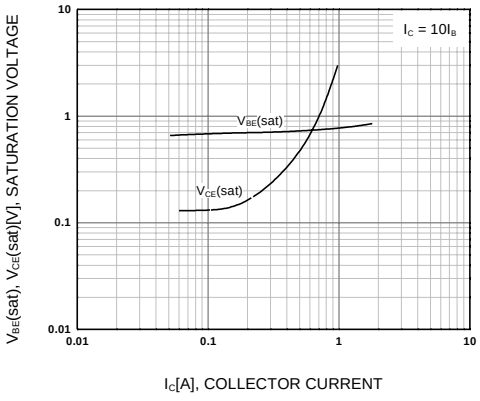


Figure 3. Base-Emitter Saturation Voltage Collector-Emitter Saturation Voltage

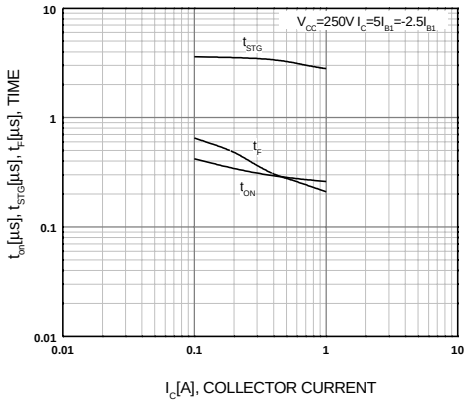


Figure 4. Switching Time

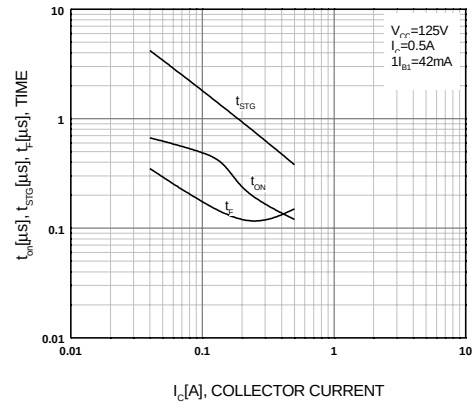


Figure 5. Switching Time

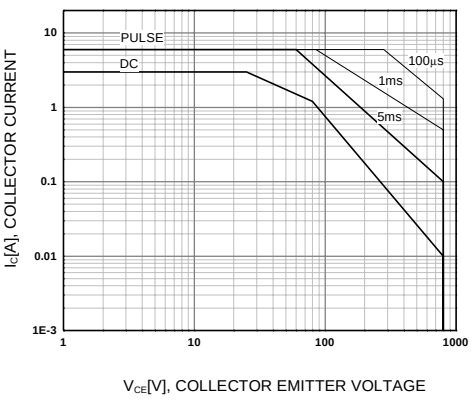


Figure 6. Safe Operating Area

Typical Characteristics (Continued)

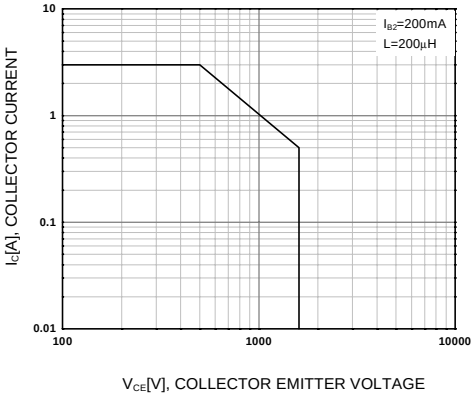


Figure 7. Reverse Bias Safe Operating Area

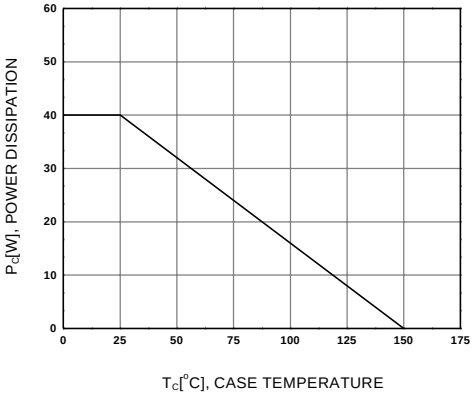
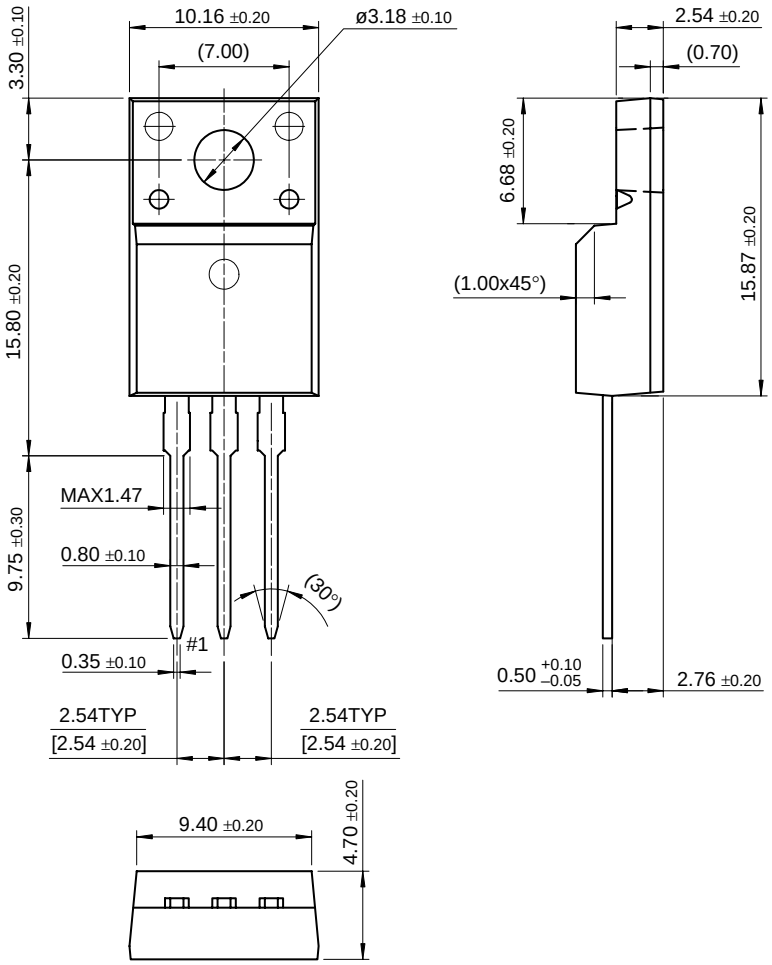


Figure 8. Power Derating

Package Demensions

TO-220F



Dimensions in Millimeters

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EcoSPARK™	ISOPLANAR™	QS™	TruTranslation™
E^2CMOS™	LittleFET™	QT Optoelectronics™	TinyLogic™
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